



Spin Hall Effect Transistor
Jörg Wunderlich, *et al.*
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The Spin Hall Effect Transistor

QO Group Meeting Jan 12th 2011, by Nathan Cheng

Outline of this talk....

- ▶ 1. End of the Silicon Road Map / Why Research Spintronics
- ▶ 2. Spin Transistor Basics: Datta-Das Paradigm
- ▶ 3. The Paper: Experimental Realization at High-T
- ▶ 4. Future Implications?

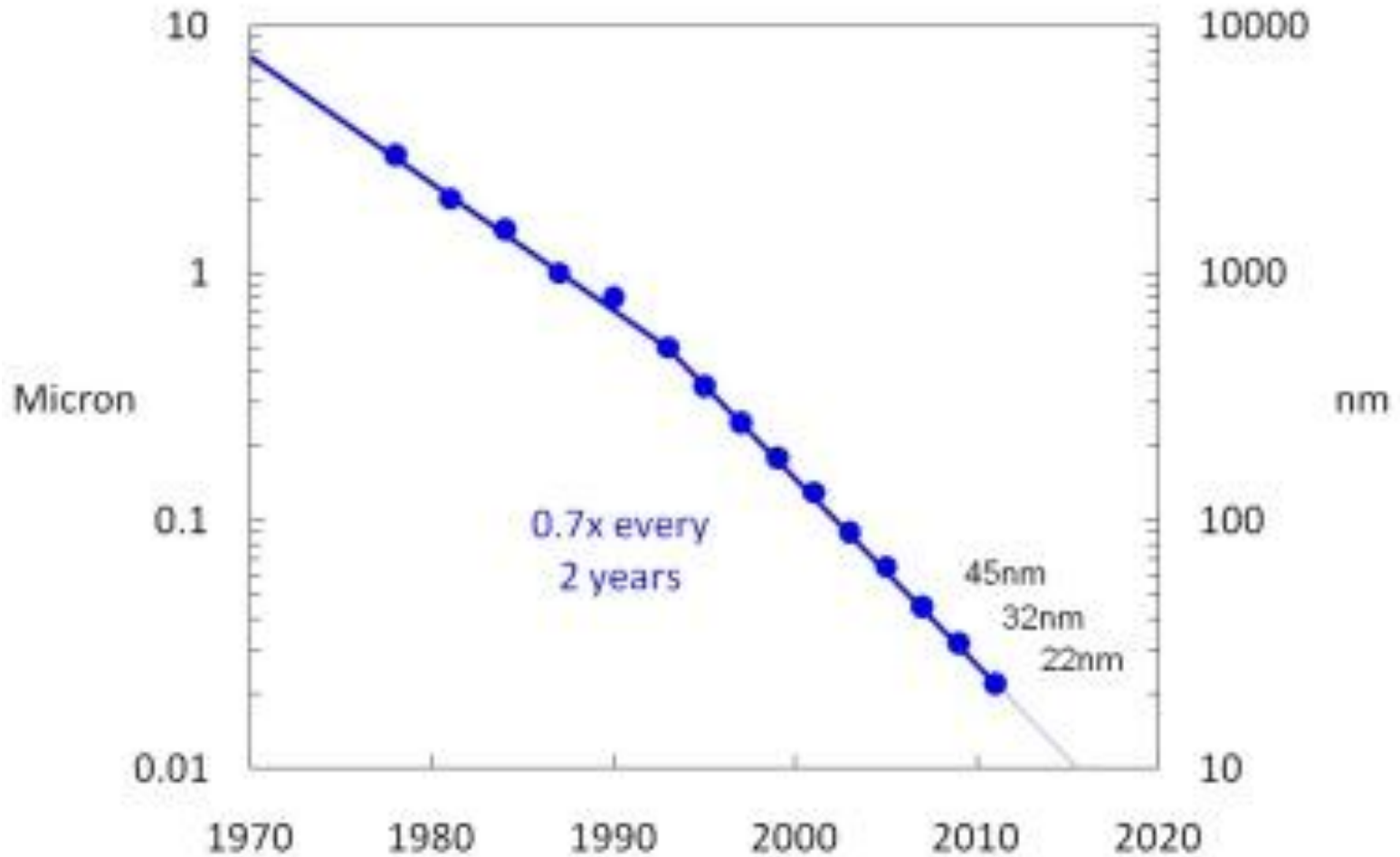


End of the road for silicon...

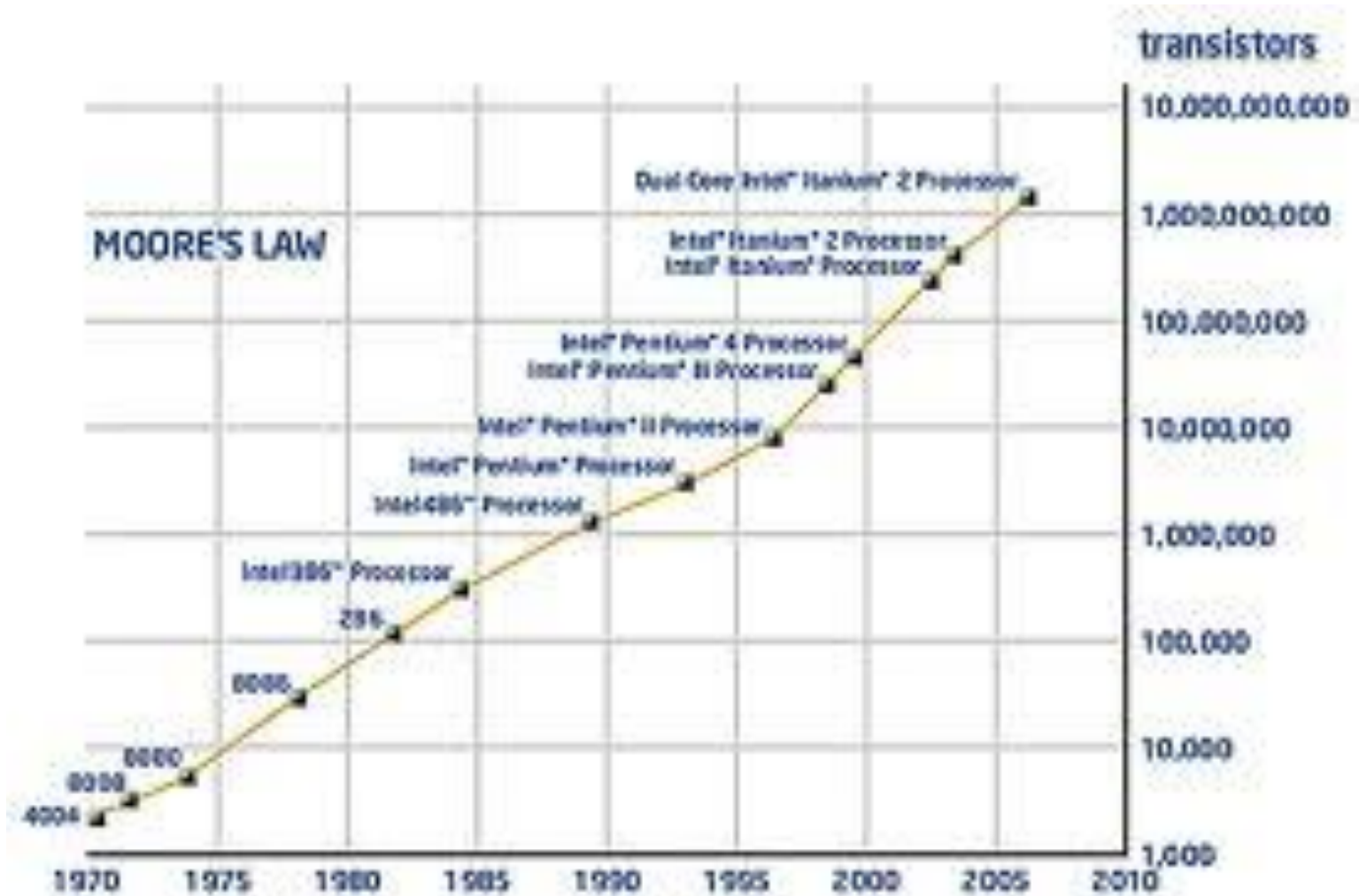
- ▶ First transistor built in 1947 by Shockley, Brattain, Bardeen.
- ▶ Metal-Oxide Semiconductor Field Effect Transistor (MOSFET) are ubiquitous!
- ▶ Transistors keep getting smaller
 - ▶ Moore's Law: Transistors per chip doubles every 2 years
 - ▶ ("Moore" like a self fulfilling prophecy!)



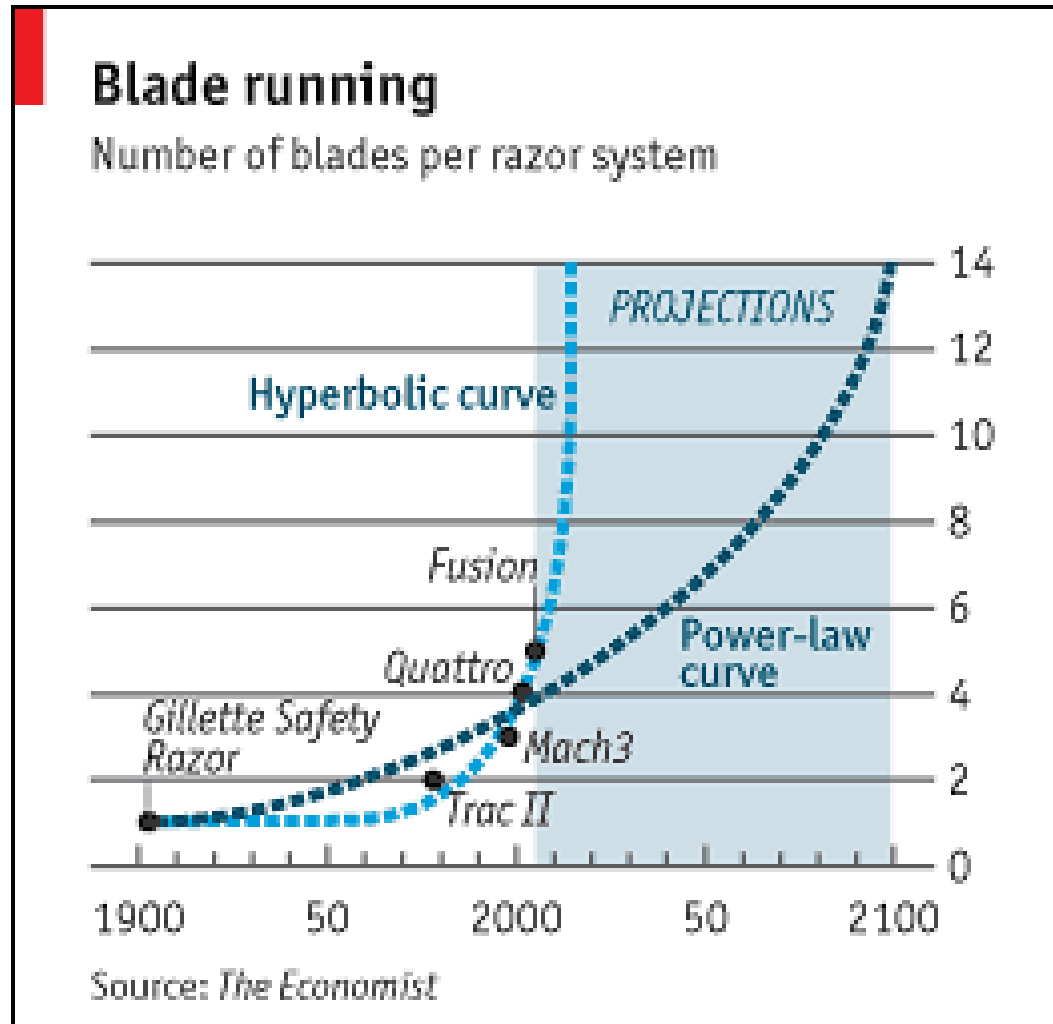
Intel: Transistor Size



Transistors per chip

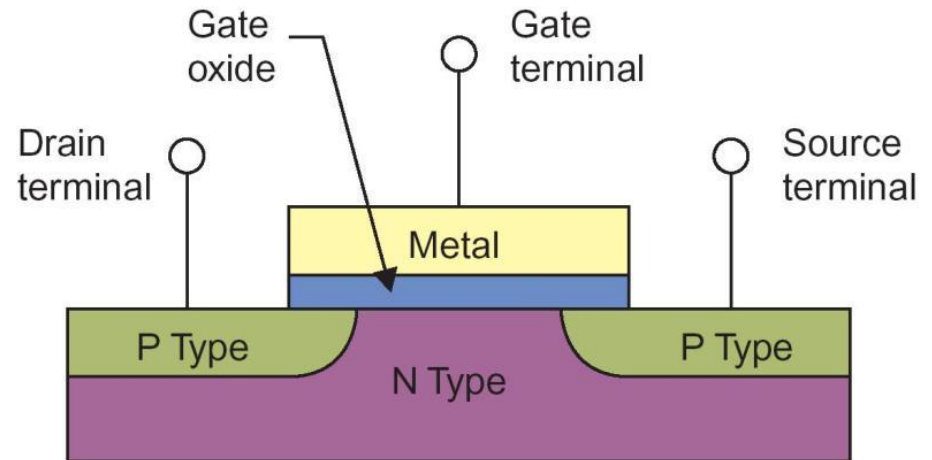
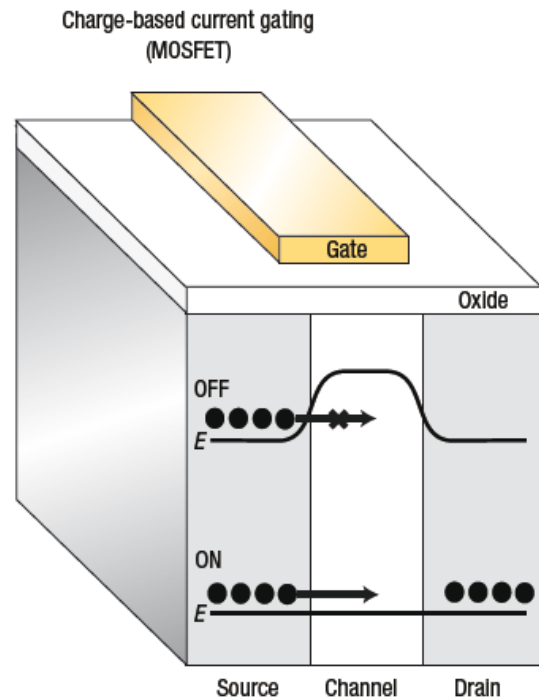


Moore's Law of Razor Blades



Main Challenges to MOSFET Miniaturization

- ▶ Gate-Channel Tunneling
- ▶ Heat dissipation
- ▶ Better lithography techniques



What's Next? Spintronics?

- ▶ Current microelectronics only utilize the charge of electrons
- ▶ Novel functionality by exploiting electron spin
 - ▶ MRAM
 - ▶ GMR / TMR magnetic read heads in hard drives
 - ▶ Transistors, logic, gates
 - ▶ Quantum computing???? (NOT covered today)



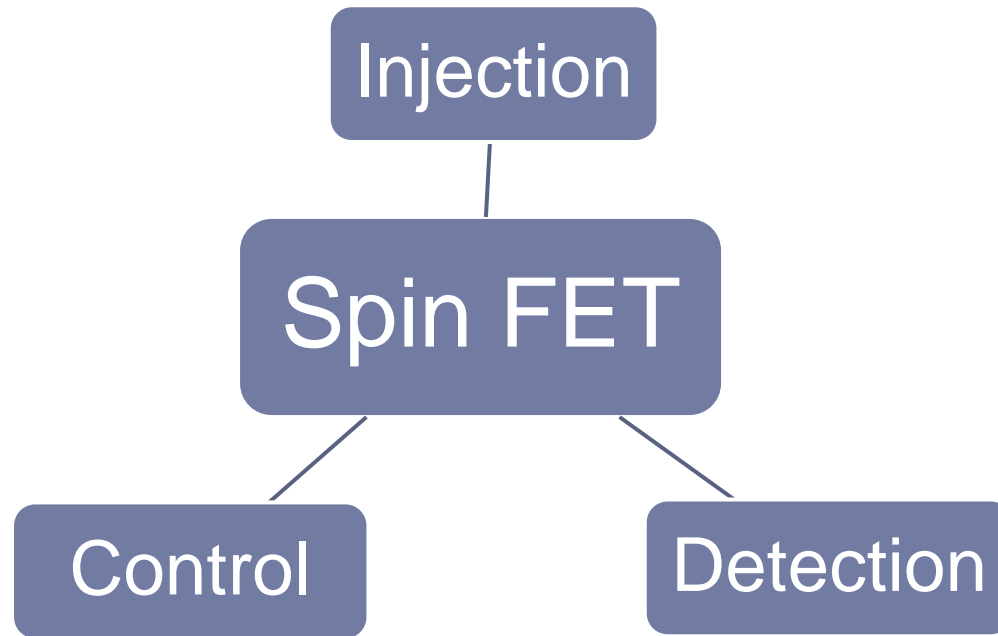
Motivation for Spintronics

- ▶ **Potential Benefits Spintronics**
- ▶ Uses less energy
 - ▶ Charge-based devices fundamental limits $\sim E \geq kT \ln(2)$
- ▶ More easily scaled
- ▶ Faster (debateable)
- ▶ Integrate with existing semiconductor technology
 - ▶ Extend Moore's Law for a bit longer



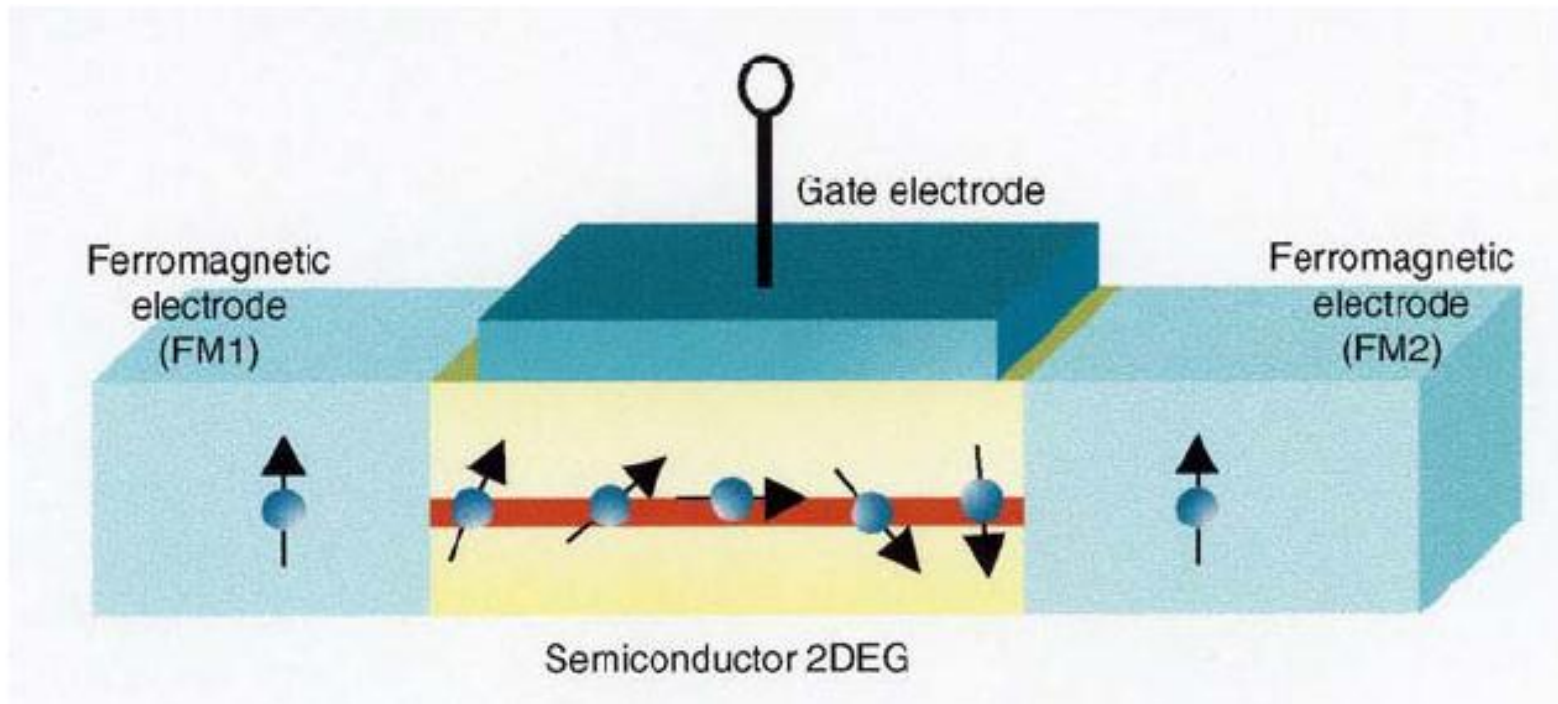
Datta-Das Spin FET: Brief Overview

- ▶ (1990) Datta-Das paper spurs new research direction
- ▶ Unrealized... OR IS IT?



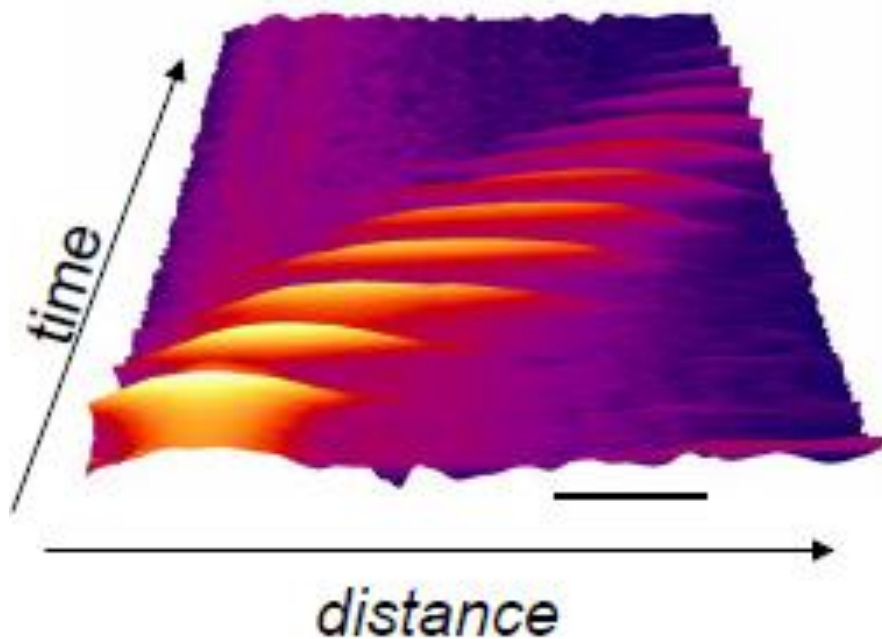
Ideal Datta-Das Spin FET

- ▶ Injection: pass current through FM electrode
- ▶ Control: Spin precession through Rashba field
- ▶ Detection: Spin polarizer



What about spin coherence?

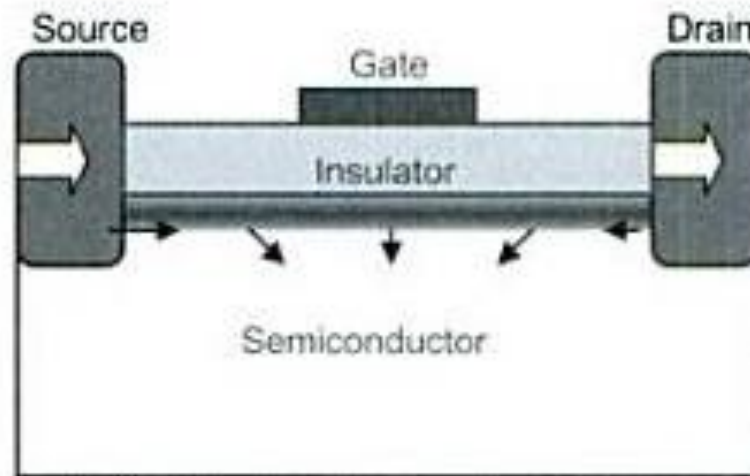
- ▶ Can be pretty good in semiconductors
 - ▶ $\tau \sim 100$ ns
 - ▶ Coherence length ~ 100 $\mu\text{m} \gg$ typical transistor channels



-
- ▶ Kikkawa and Awschalom, Nature 397, 139 (1999)

Spin Manipulation, SO coupling

- ▶ How to change the spin electrically?
- ▶ Take advantage of spin-orbit coupling interaction
 - ▶ Simplified case: 1D channel, fully polarized spin current

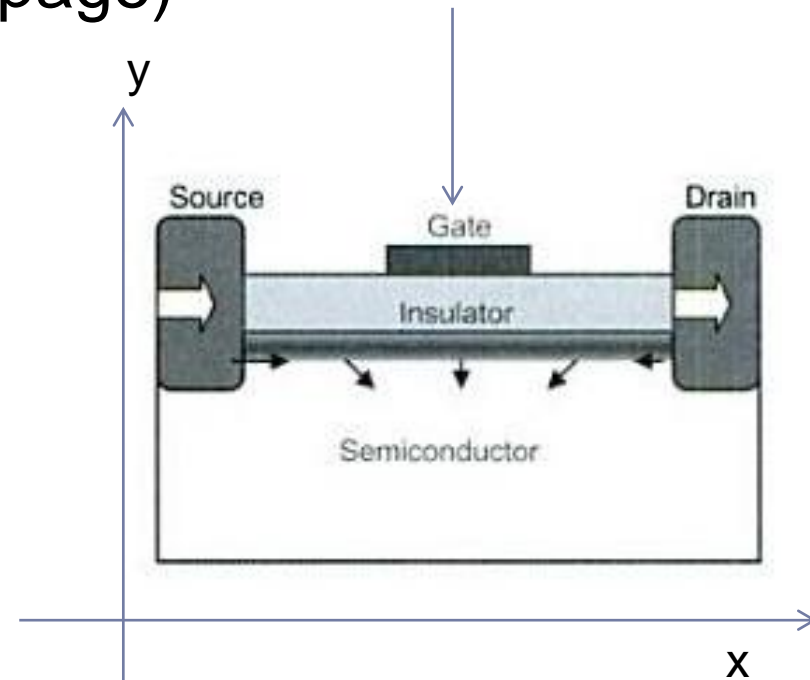


Rashba Field SO

- ▶ Electric field (from asymmetry and applied field) is seen as B-field in electron rest frame

- ▶ $B_{eff} = \frac{2m^*}{eh^2} \alpha E_y v_x$ (out of page)

- ▶ α = Rashba coefficient
- ▶ m = effective mass
- ▶ v = drift velocity



Rashba Field

▶ $B_{eff} = \frac{2m^*}{eh^2} \alpha E_y v_x$ (out of page)

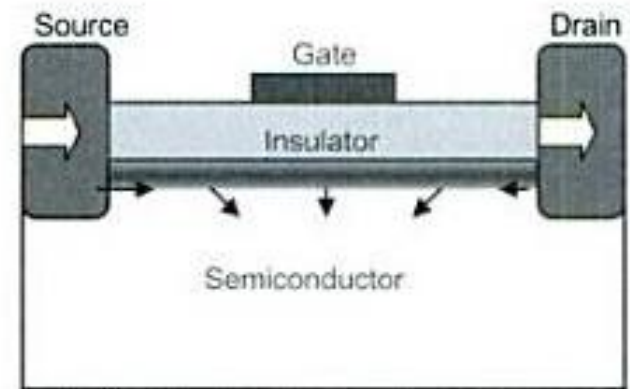
▶ B depends on the transverse E-field

▶ B is perpendicular to spin

▶ $\langle S_x \rangle$ precess about B (Larmor)

▶ Current ON if S_x aligned to Drain

▶ Current OFF if S_x is anti-aligned



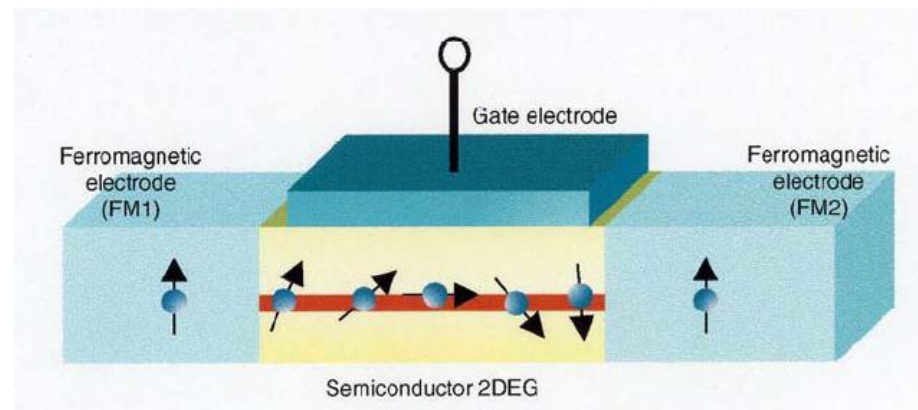
SO coupling in semiconductors

- ▶ Actually can be much more complicated
 - ▶ Involves Dirac Equation and information on band structure
- ▶ Band and crystal structure play an important roles
 - ▶ Other effects include Dresselhaus spin-orbit coupling
- ▶ Basic qualitative picture remains the same: Electric field can induce precession

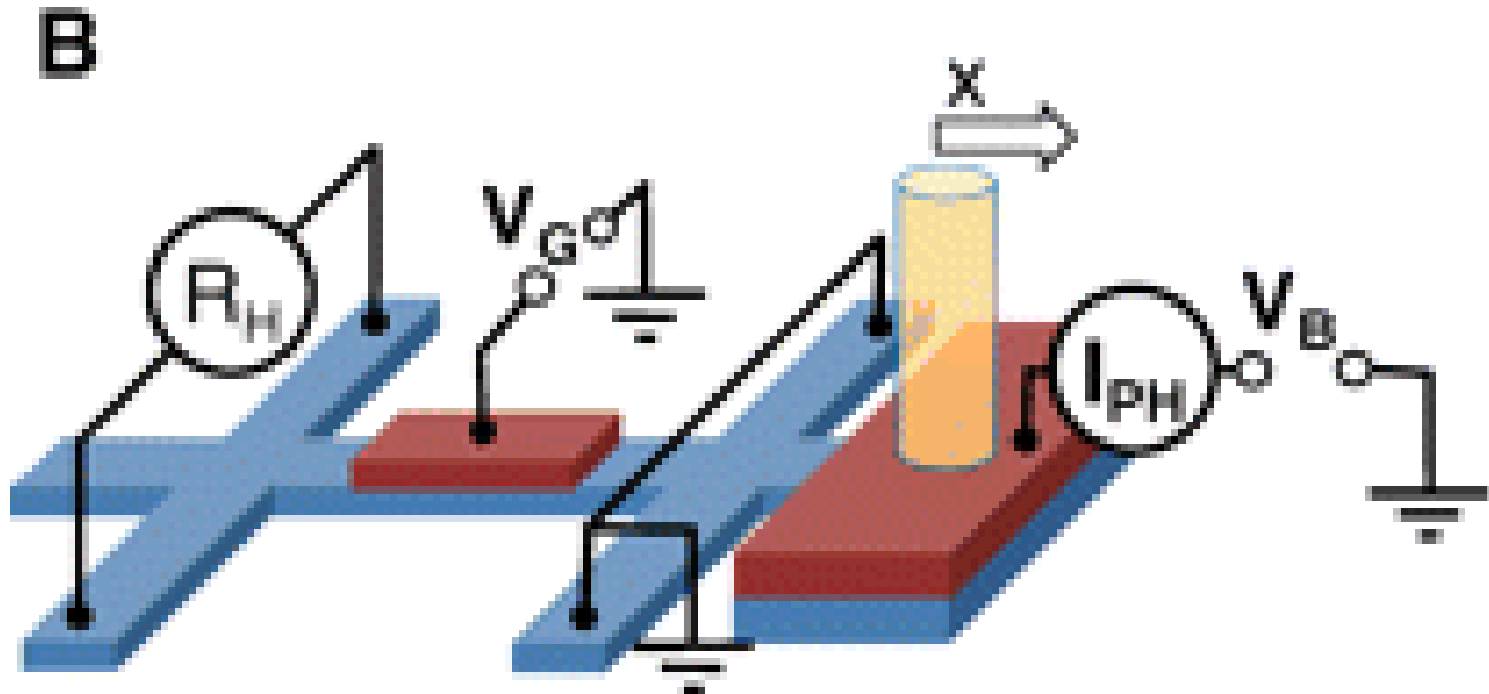


Limitations of Datta-Das

- ▶ Ferromagnetic contacts introduce stray magnetic fields
- ▶ Poor spin injection efficiency going from ferromagnetic contact to semiconductor
 - ▶ Lots of research on magnetic semiconductors
 - ▶ Difficult to find the right materials at high-T

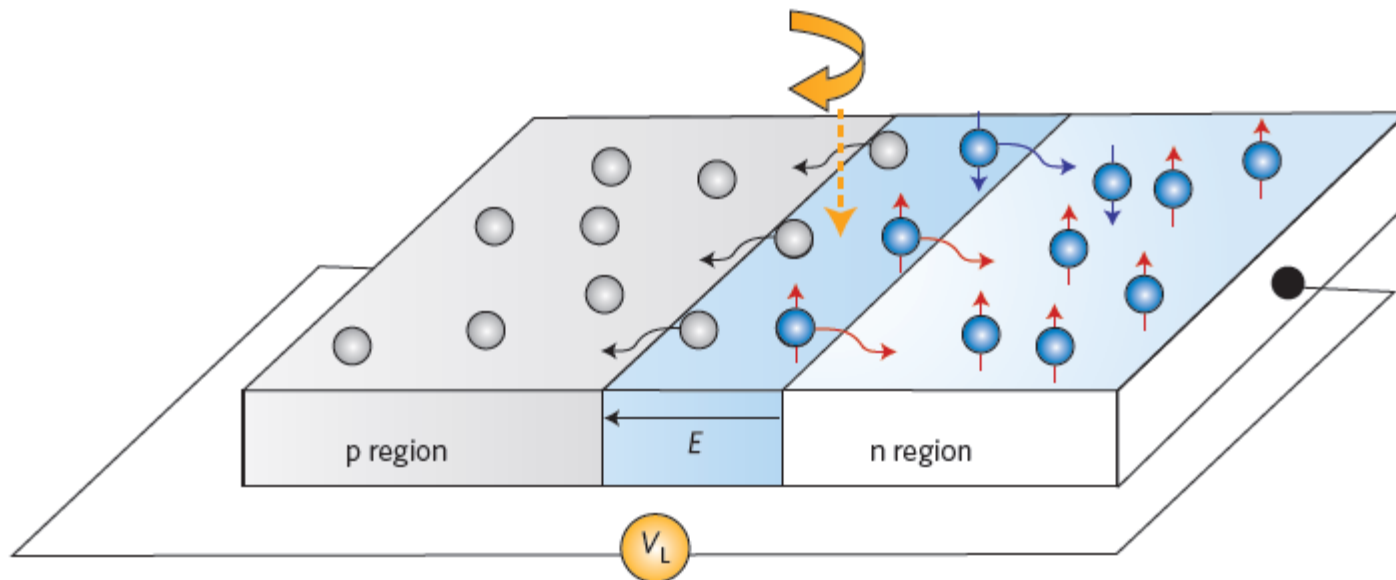


FINALLY: The Spin Hall Effect Transistor

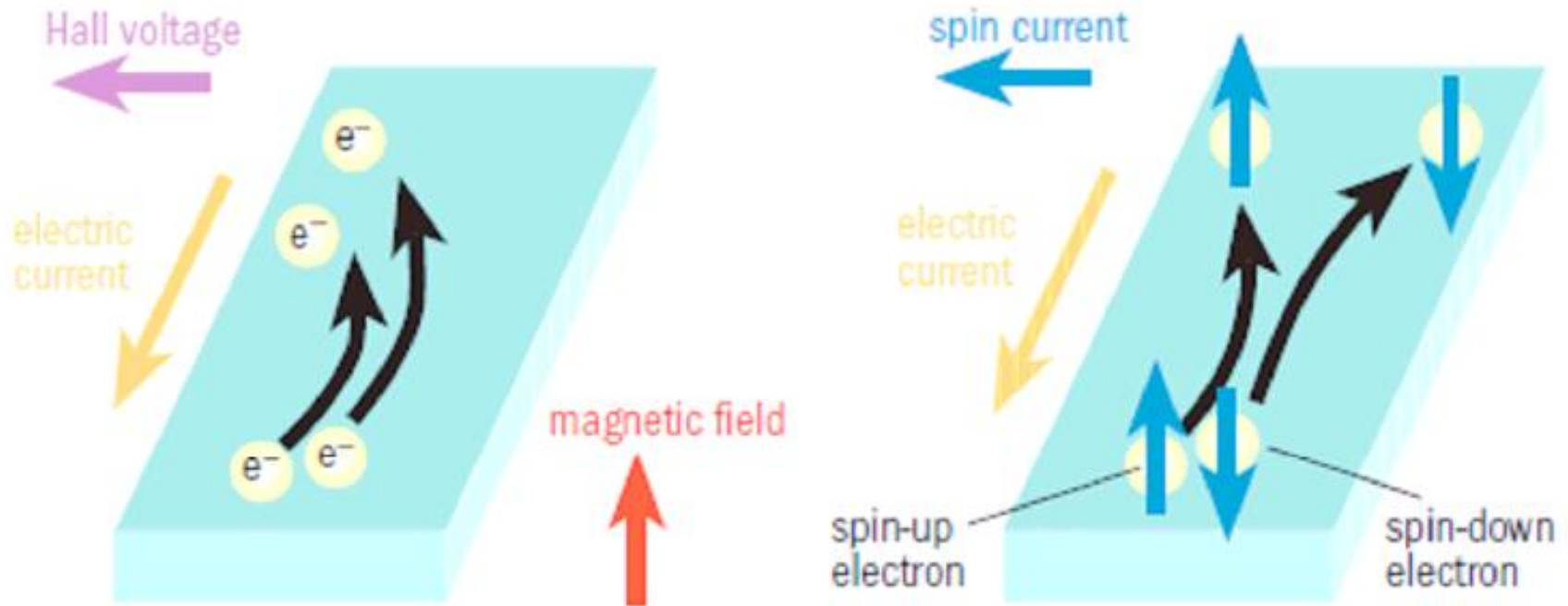


Optical Spin Injection

- ▶ Use circularly polarized light!
 - ▶ PN junction operated like a photodiode (i.e solar) cell
 - ▶ Electron-hole pairs are formed
- ▶ E-H spin determined by optical selection rules
 - ▶ e- Polarization depends on circularity and sense of light



Spin Hall Effect (SHE)



Intuitively like Magnus effect (i.e Bend it like Beckham)



Detection: Spin Hall Effect (SHE)

- ▶ Predicted by M.I. Dyakonov and V.I. Perel in 1971
 - ▶ Always caused by some kind of spin-orbit coupling
 - ▶ *Not detected until 2004!*

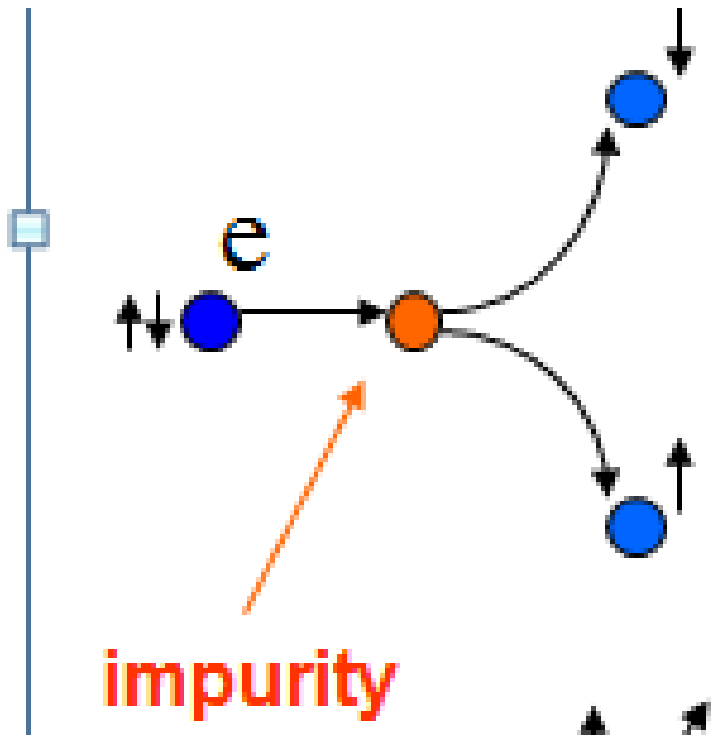
- ▶ *Extrinsic SHE*
 - ▶ *Occurs from electrons scattering with impurities*
 - ▶ *“Skew-scattering”*
 - ▶ *Primary contributor for our device*

- ▶ *Intrinsic SHE*
 - ▶ *Spin dependent band structure*



Skew Scattering in 2D

- ▶ Skew scattering is spin dependent due to spin-orbit coupling interactions between electron and impurity



Skew scattering

More spin up electrons are deflected to the right than to the left (and viceversa for spin down)

Electron sees $\mathbf{B} \sim \mathbf{v} \times \mathbf{E}$ (relativity)

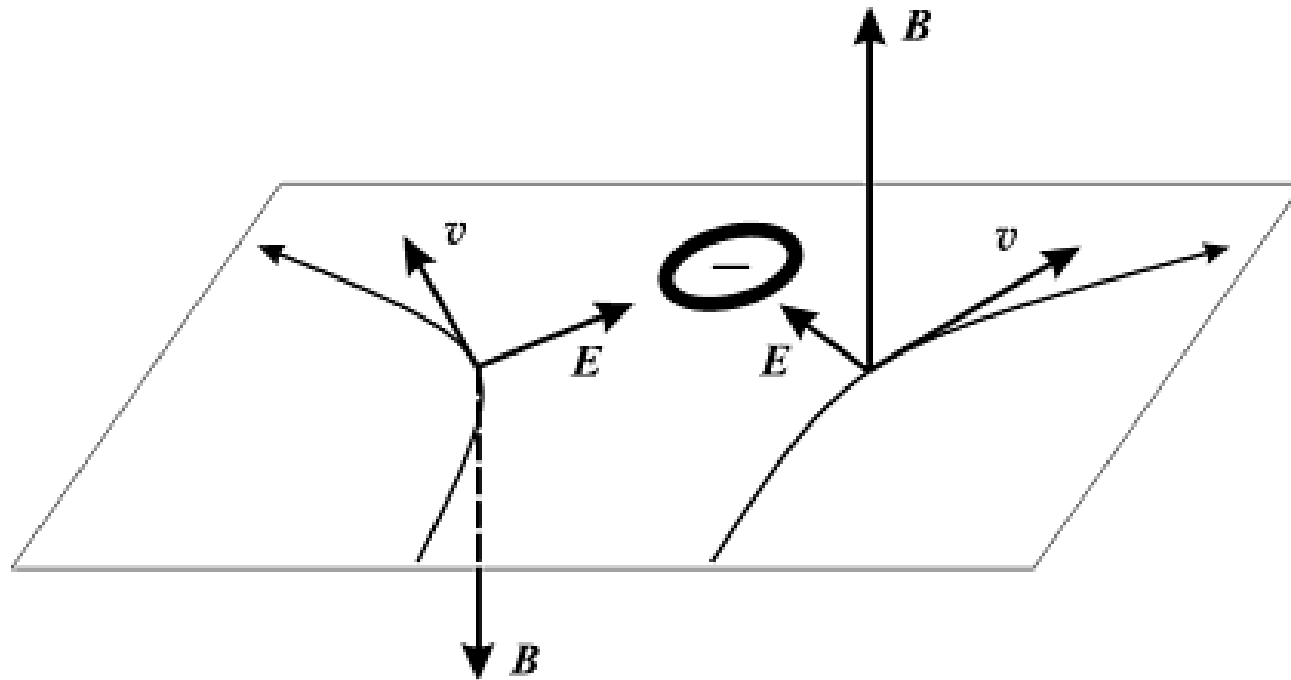
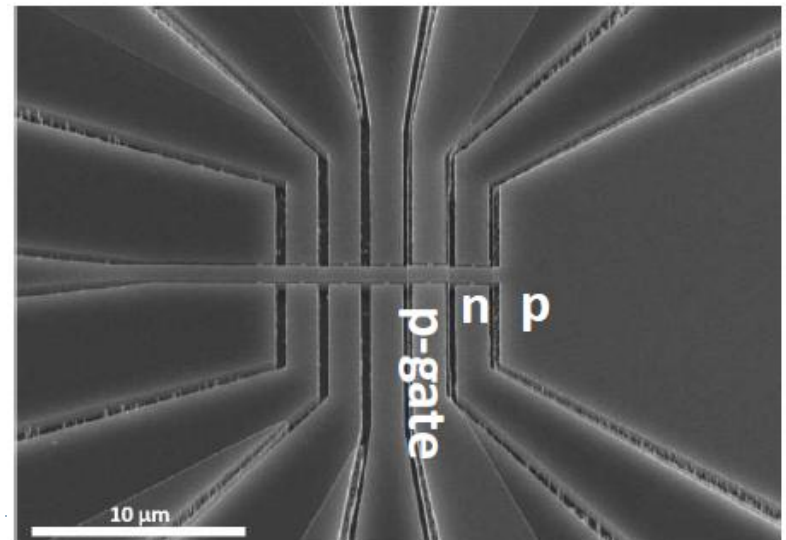
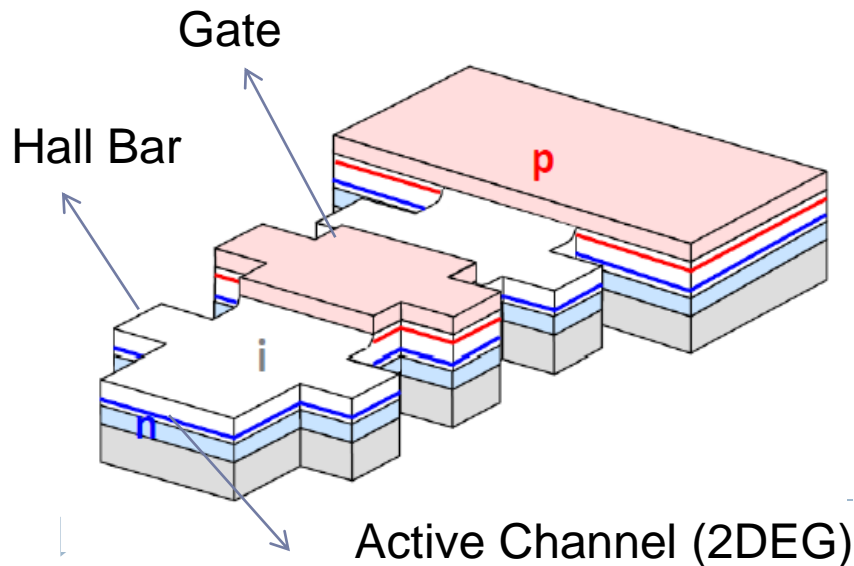


Fig. 8.3. Schematics of electron scattering by a negative charge. The electron spin sees a magnetic field $\mathbf{B} \sim \mathbf{v} \times \mathbf{E}$ perpendicular to the plane of the electron trajectory. Note that the magnetic field has opposite directions for electrons scattered to the left and to the right



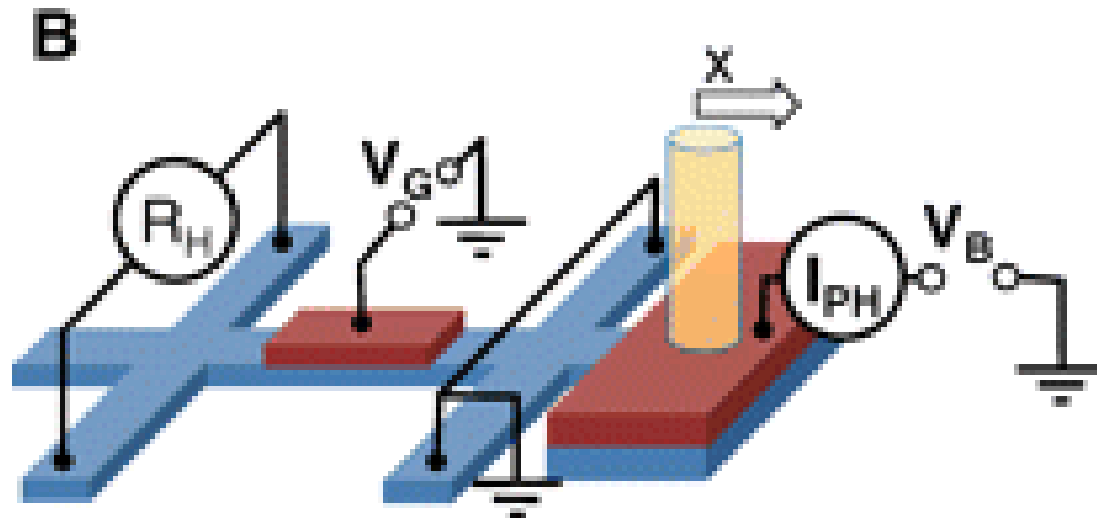
Wunderlich et al: Basic idea

- ▶ Similar to the Datta-Das Spin FET
- ▶ Complicated doped Al/Ga/As (PIN) heterojunction
 - ▶ Tune all those SO coupling interactions
- ▶ Optical spin current injection
- ▶ Rashba Field Spin precession (same as Datta-Das)



SHE Transistor cont...

- ▶ Ti-Saph laser 870 nm (circularly polarized)
- ▶ V_b = (reverse) bias voltage = -10V
- ▶ I_{PH} = photocurrent
- ▶ Twist! *Electric* current is drained off before the gate.
 - ▶ Diffusive spin transport



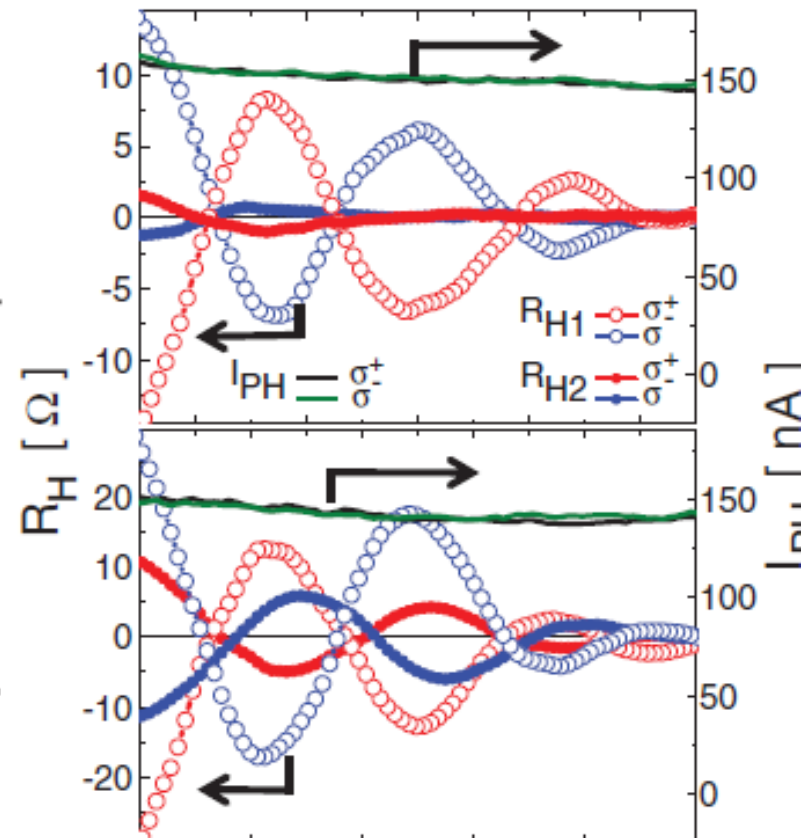
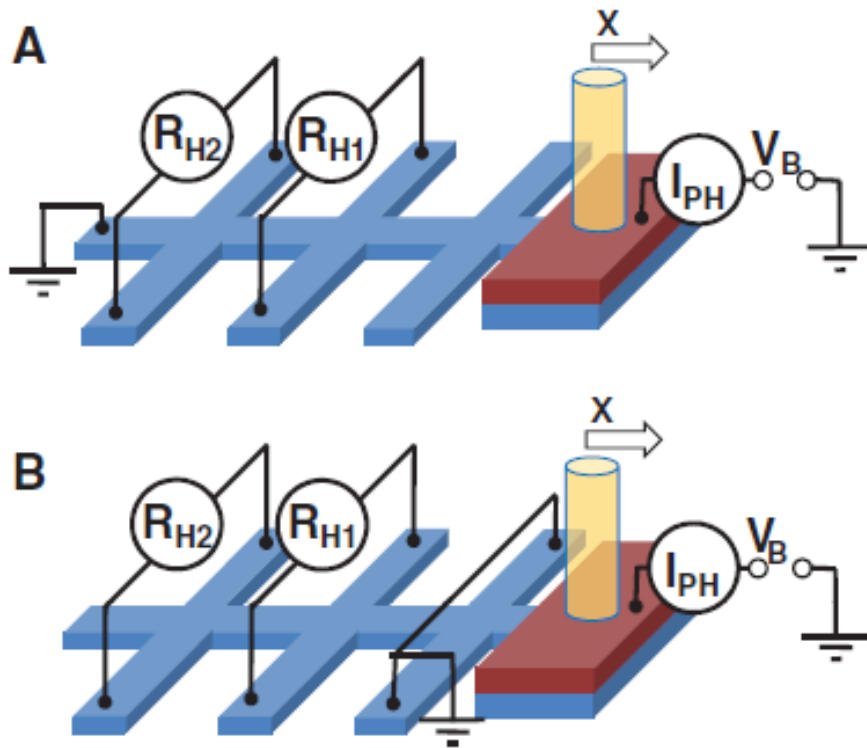
Recap

- ▶ 1. Optical spin injection: Spin polarized photocurrent
- ▶ 2. Spin current polarization modulated via Rashba field (effective B-field + Larmor precession)
- ▶ 3. Spin Hall Effect causes accumulation of different spins to opposite (transverse sides).
- ▶ 4. Because we start with a spin polarized current, we get a charge imbalance => electrically detectable



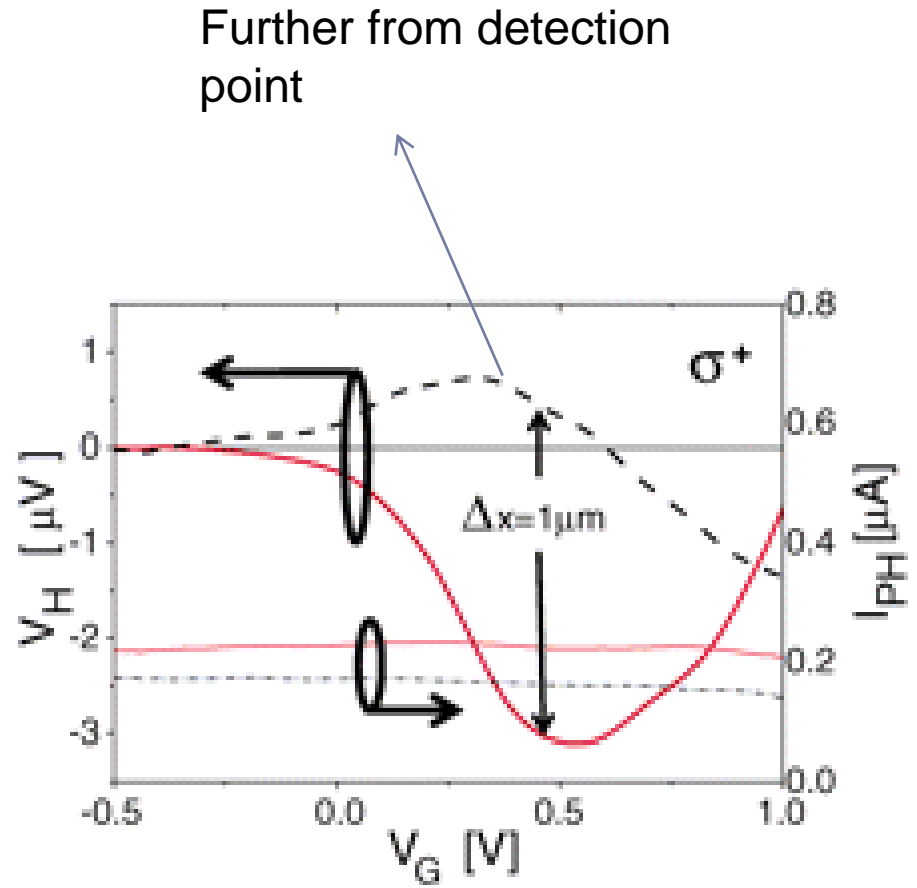
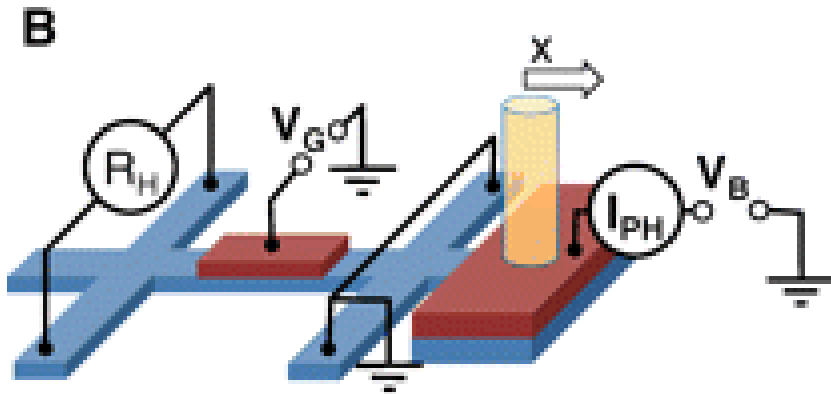
Recap continued...

► Typical setups

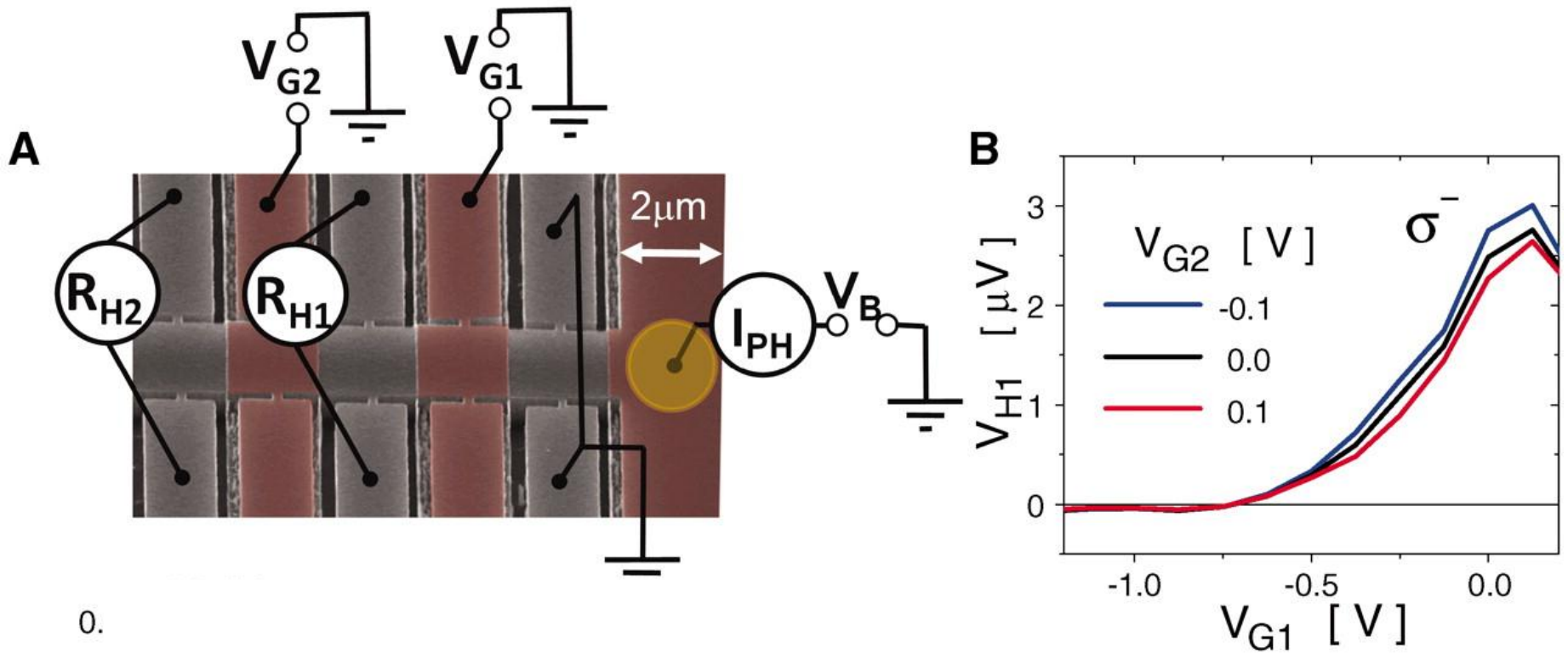


Gate action

- ▶ $R_H = \frac{V_H}{I_{PH}}$
- ▶ $V_g = \text{gate voltage}$



Double Gate Action!



Impact

- ▶ Finally, a (very close) realization Datta-Das spin transistor (proposed 20 years ago)
 - ▶ Demonstrable logic function using spin current
- ▶ Works at high-temperature
- ▶ All semiconductor, electrical detection
 - ▶ Possible integration with current technology
- ▶ Higher Spin Hall Voltages
 - ▶ Usually pretty small



The Future

- ▶ Optical injection is not very scalable at the moment
- ▶ Two-stage driving requires amplification
- ▶ Can use the semiconductor as a solid state polarimeter.
 - ▶ Measure blood sugar levels quickly?



THE END

- ▶ Thanks for your attention!

